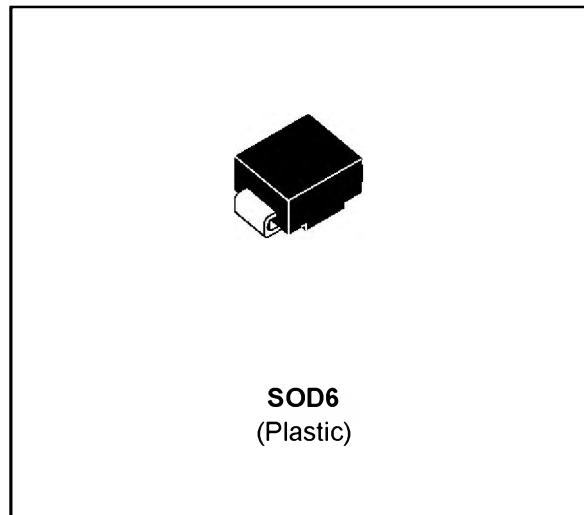


**FAST RECOVERY RECTIFIER DIODES**
**FEATURES**

- VERY LOW REVERSE RECOVERY TIME
- VERY LOW SWITCHING LOSSES
- LOW NOISE TURN-OFF SWITCHING
- SURFACE MOUNT DEVICE

**DESCRIPTION**

Single high voltage rectifier ranging from 200V to 400 V suited for Switch Mode Power Supplies and other power converters.


**ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter		Value	Unit
$I_{F(RMS)}$	RMS forward current		10	A
$I_{F(AV)}$	Average forward current	$T_I=110^{\circ}\text{C}$ $\delta = 0.5$	1	A
$I_{FSM}$	Non repetitive surge peak forward current	$t_p=10\text{ms}$ sinusoidal	30	A
$T_{stg}$ $T_j$	Storage and junction temperature range		- 40 to + 150 - 40 to + 150	$^{\circ}\text{C}$ $^{\circ}\text{C}$

Symbol	Parameter	SMBYT01-			Unit
		200	300	400	
$V_{RRM}$	Repetitive peak reverse voltage	200	300	400	V

**THERMAL RESISTANCE**

Symbol	Parameter	Value	Unit
$R_{th(j-l)}$	Junction-leads	25	$^{\circ}\text{C/W}$

## SMBYT01

### ELECTRICAL CHARACTERISTICS STATIC CHARACTERISTICS

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
$V_F$ *	$T_j = 25^\circ\text{C}$	$I_F = 1\text{ A}$			1.5	V
	$T_j = 100^\circ\text{C}$				1.4	
$I_R$ **	$T_j = 25^\circ\text{C}$	$V_R = V_{RRM}$			20	$\mu\text{A}$
	$T_j = 100^\circ\text{C}$				0.5	mA

Pulse test : \*  $t_p = 380\ \mu\text{s}$ , duty cycle < 2 %

\*\*  $t_p = 5\ \text{ms}$ , duty cycle < 2 %

### RECOVERY CHARACTERISTICS

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
trr	$T_j = 25^\circ\text{C}$	$I_F = 0.5\text{A}$ $I_{rr} = 0.25\text{A}$ $I_R = 1\text{A}$			25	ns
		$I_F = 1\text{A}$ $dI_F/dt = -15\text{A}/\mu\text{s}$ $V_R = 30\text{V}$			60	

### TURN-OFF SWITCHING CHARACTERISTICS (Without serie inductance)

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
$t_{IRM}$	$V_{CC} = 200\text{V}$ $T_j = 100^\circ\text{C}$	$I_F = 1\text{A}$ $L_p \leq 0.05\ \mu\text{H}$		35	50	ns
$I_{RM}$		$dI_F/dt = -50\text{A}/\mu\text{s}$		1.5	2	A

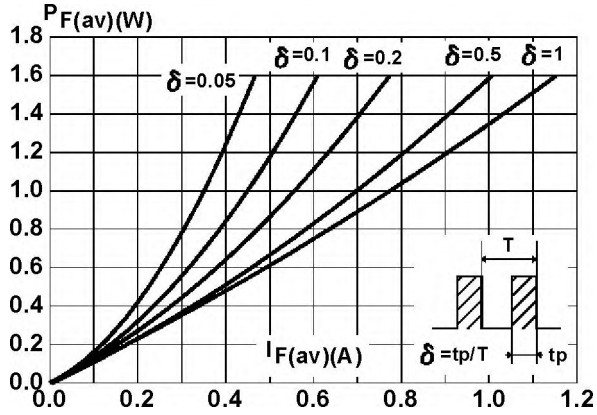
To evaluate the conduction losses use the following equation :

$$P = 1.1 \times I_{F(AV)} + 0.25 \times I_{F(RMS)}^2$$

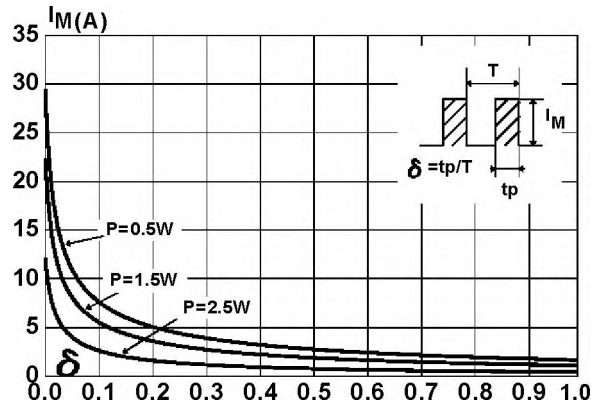
<b>Voltage (V)</b>	200	300	400
<b>Marking</b>	B2	B3	B4

Laser marking  
Logo indicates cathode

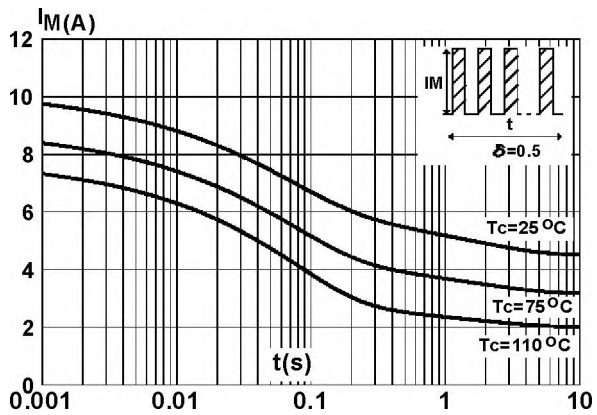
**Fig.1** : Low frequency power losses versus average current.



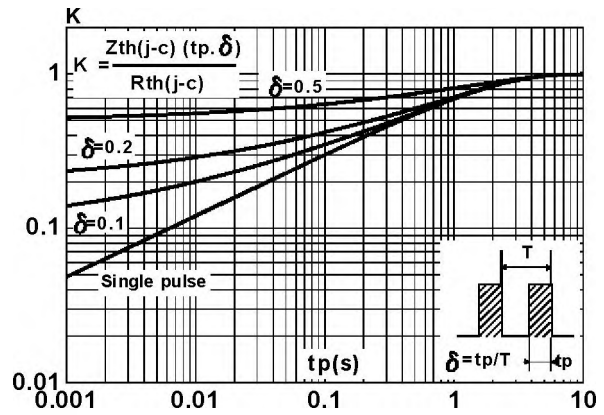
**Fig.2** : Peak current versus form factor.



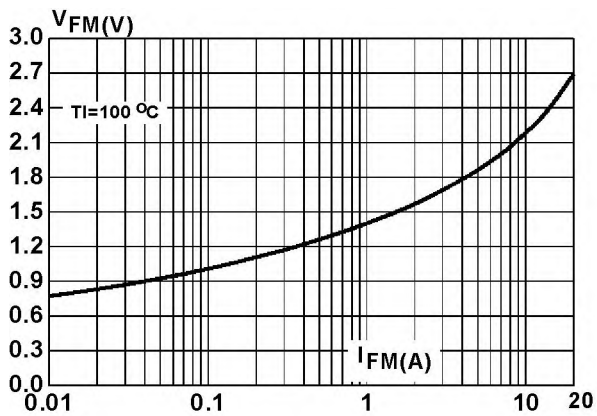
**Fig.3** : Non repetitive surge peak forward current versus overload duration.



**Fig.4** : Relative variation of thermal impedance junction to lead versus pulse duration.



**Fig.5** : Voltage drop versus forward current. (Maximum values)



**Fig.6** : Average current versus ambient temperature. (duty cycle : 0.5)

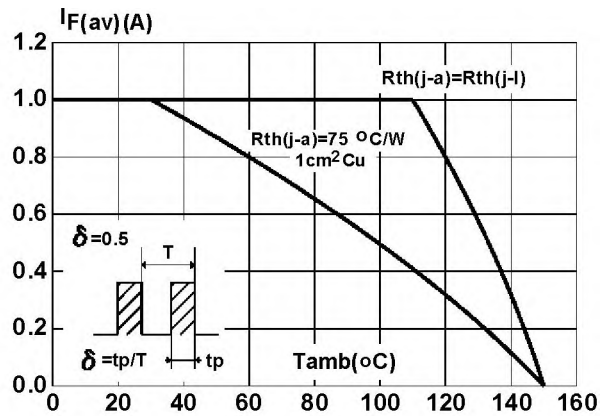


Fig.7 : Recovery time versus  $di_F/dt$ .

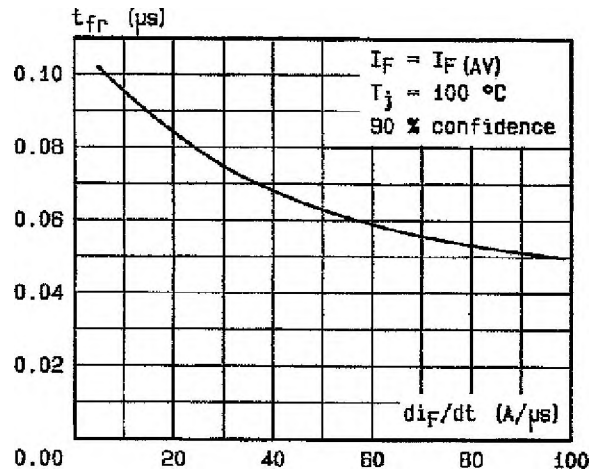


Fig.9 : Peak reverse current versus  $di_F/dt$ .

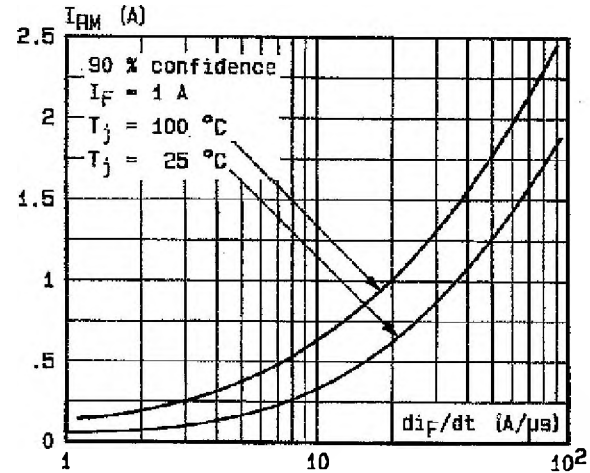


Fig.11 : Dynamic parameters versus junction temperature.

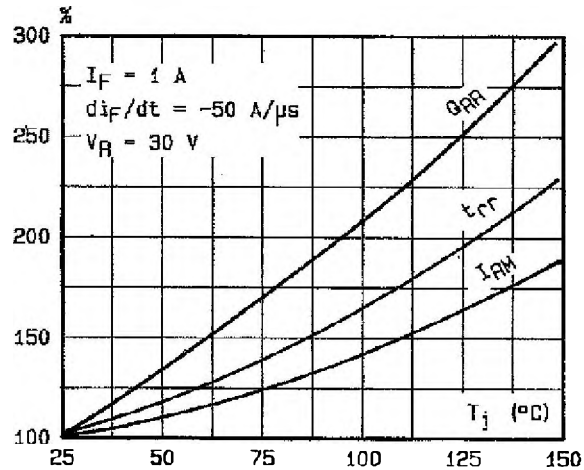


Fig.8 : Peak forward voltage versus  $di_F/dt$ .

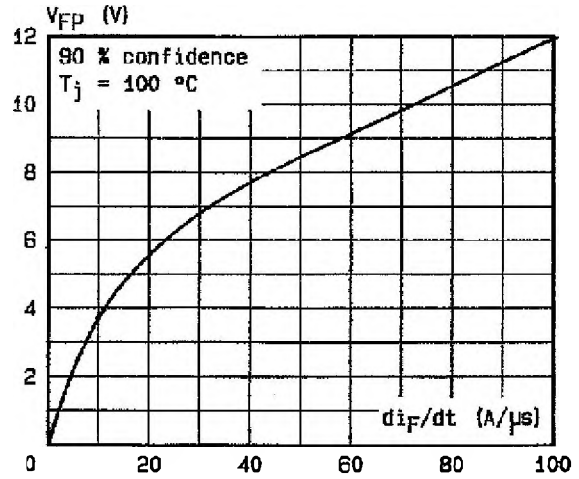


Fig.10 : Recovery charge versus  $di_F/dt$ . (typical values)

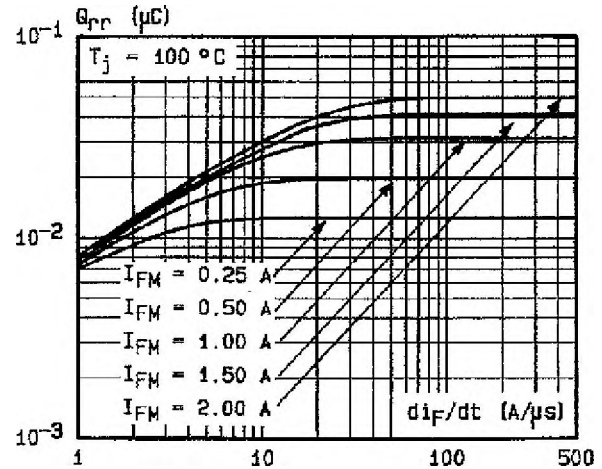
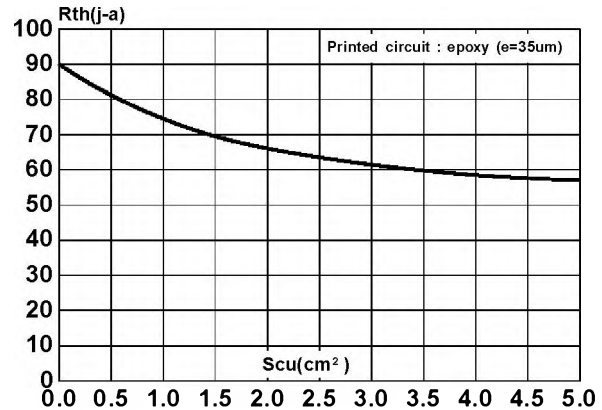
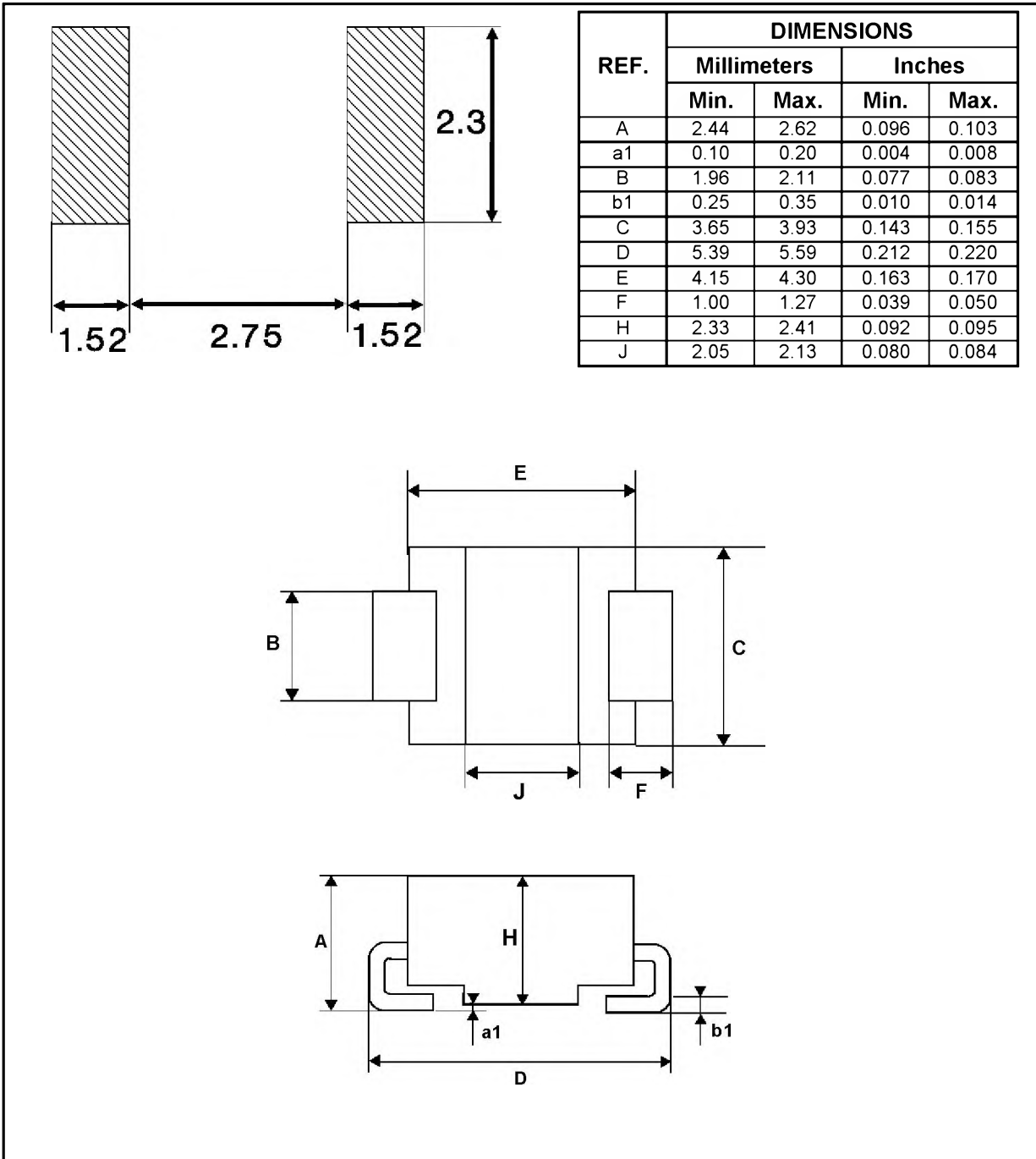


Fig.12 : Thermal resistance junction to ambient versus copper surface under each lead.



PACKAGE MECHANICAL DATA  
SOD6



Laser Marking  
Logo indicated cathode

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